Enhanced hydrodynamic transport in near magic angle twisted bilayer graphene

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Using the semiclassical quantum Boltzmann theory and employing the Dirac model with twist angledependent Fermi velocity, we obtain results for the electrical resistivity, the electronic thermal resistivity, the Seebeck coefficient, and the Wiedemann-Franz ratio in near magic angle twisted bilayer graphene, as functions of doping density (around the charge-neutrality point) and modified Fermi velocity \tilde{v} . The \tilde{v} dependence of the relevant scattering mechanisms, i.e., electron-hole Coulomb, long-range impurities, and acoustic gauge phonons, is considered in detail. We find a *range* of twist angles and temperatures, where the combined effect of momentum-nonconserving collisions (long-range impurities and phonons) is minimal, opening a window for the observation of strong hydrodynamic transport. Several experimental signatures are identified, such as a sharp dependence of the electric resistivity on doping density and a large enhancement of the Wiedemann-Franz ratio and the Seebeck coefficient.

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I. INTRODUCTION

Since the 2018 discovery of exotic superconductivity and correlated insulating phases in magic angle twisted bilayer graphene (tBLG) [1-3], this system has been the subject of many theoretical and experimental investigations; e.g., see Ref. [4] and references therein. The intense interest arises mainly from the new physics brought in by the low-lying flat bands near magic angles in tBLG [5]. The average Coulomb interaction [6,7] between the quasiparticles in narrow bands is far larger than the kinetic energy, giving access to a strongly correlated regime and providing an ideal system for the observation of collective many-body phenomena.

In this paper, we focus on a particular collective phenomenon, namely, hydrodynamic transport in tBLG. Hydrodynamic transport is expected whenever the momentumconserving collisions between particles are much more frequent than the momentum-nonconserving collisions with impurities and/or lattice vibrations (phonons). In addition, umklapp processes must be negligible. Under these conditions, the electric and thermal transport can be described by hydrodynamic equations for the flow of quasiparticleselectrons in the conduction band and holes in the valence band. Close to the charge-neutrality point (CNP), where the densities of electrons and holes are nearly equal, a key indicator of the hydrodynamic regime is the ratio $\gamma = \tau_d/\tau_{eh}$ between the electron-hole scattering rate $1/\tau_{eh}$ and the singleparticle scattering rate $1/\tau_d$ from momentum-nonconserving collisions with impurities and phonons. A large value of $\gamma \gg 1$ defines the so-called hydrodynamic transport window [8], which has been theoretically predicted and experimentally observed in single-layer graphene [9,10], as well as in ABstacked bilayer graphene [10–14].

One important finding of the present work is that for some of the experimental samples in the literature, e.g., Refs. [3,15], these are already of sufficiently low disorder that our formalism predicts a robust hydrodynamic window close to twist angle of 1.11° . (From the very low-temperature electrical transport, we estimate a charged impurity density of 1.6×10^{11} cm⁻² for sample D5 in [3].) Other groups have data [1] where the impurity concentration is just above the threshold to observe hydrodynamic features and, therefore, the predictions we make below should be seen in cleaner samples in the near future.

In the hydrodynamic regime, the electric and thermal transport have distinctive features that are described by the following expressions for the electric resistivity ρ_{el} and the thermal resistivity ρ_{th} , as functions of the dimensionless doping away from charge neutrality $\bar{\mu} \equiv \mu/(k_B T)$:

$$\rho_{\rm el}(\bar{\mu}) \simeq \rho_{\rm C} \frac{\Gamma^2}{\Gamma^2 + (\alpha \bar{\mu})^2},\tag{1}$$

$$\rho_{\rm th}(\bar{\mu}) \simeq \rho_{\rm C} [\Gamma^2 + (\alpha \bar{\mu})^2] \left(\frac{e^2}{k_B^2 T}\right),\tag{2}$$

where $\alpha = 4 \ln 2/9\zeta(3) \approx 1/4$ is constant and $\bar{\mu} \ll 1$. In these formulas, $\rho_C \propto 1/(e^2 \tau_{eh})$ is the electric resistivity due to Coulomb electron-hole scattering at the CNP [12,16–18], and $\Gamma = (k_B/e)\sqrt{T\rho_{th}(0)/\rho_C}$, where $\rho_{th}(0)$ is the thermal resistivity at charge neutrality, which is due to momentumnonconserving collisions only because the thermal current density coincides with the conserved momentum density at the CNP. Making use of the conventional Wiedemann-Franz law for noninteracting systems, we can express Γ more incisively as a ratio of disorder and interaction contributions to the electric resistivity, i.e.,

$$\Gamma \simeq 0.35 \sqrt{\frac{\rho_{\rm el,d}(0)}{\rho_{\rm C}}} \propto \frac{1}{\gamma^{1/2}},\tag{3}$$

and $\rho_{el,d}(0)$ is the noninteracting electric resistivity collisions. Thus, we see that the cumulative effect of all types of disorder, e.g., charged impurities, phonons, etc., is included in the single parameter Γ , which becomes effectively a measure of "hydrodynamicity."

As shown in Ref. [18], the derivation of Eqs. (1) and (2) requires that the conditions $\Gamma^2 \ll 1$ and $\bar{\mu} \ll 1$ be satisfied. These conditions define a temperature window for the observation of hydrodynamic effects: $\bar{\mu} \ll 1$ implies that the temperature is not too low and $\Gamma \ll 1$ excludes high temperatures, where the phonon contribution to the resistivity would become very large. In practice, intermediate temperatures in a 50–100 K range are most suitable. Equations (1) and (2) provide us with explicit analytical expressions for the resistivities as functions of doping density, via the chemical potential.

Following the theory outlined above, the purpose of this paper is to understand how the electric and thermal resistivity, as well as the Wiedemann-Franz (WF) and the Seebeck coefficient, behave as functions of the angle-dependent Fermi velocity in tBLG near charge neutrality. While employing a linear Dirac model to describe the low-energy bands of tBLG, we note that the twist angle acts as a new knob to vary the Fermi velocity and thus the strength of interactions. An incomplete theory, taking into account only electron scattering from long-range impurities, would suggest hydrodynamic effects to gain strength at higher temperatures and as the magic angle is approached. Careful consideration of the role of gauge phonons, which remain unscreened and contribute strongly to the resistivity [19], reveals quite a different reality. A strong hydrodynamic regime is found in the vicinity of the magic twist angle and at rather low-temperature range $(10 \lesssim T \lesssim 50 \text{ K})$ compared to single and bilayer graphene systems [12,18]. This enhanced hydrodynamic is traced back to the strong suppression of electronic screening in tBGL near the magic angle.

Experimentally, the signature of the hydrodynamic regime should be clear and strong in the electrical resistivity, which is predicted to decrease sharply as a function of increasing doping density as nearly free electrons become available for conduction [see Fig. 3(a)]. By contrast, the noninteracting electric resistivity is nearly independent of density, as seen by comparing Figs. 3(a) and 3(b). Differently stated, Eq. (1) predicts that the electric conductivity (inverse of the resistivity) grows as $\bar{\mu}^2/\Gamma^2$ as one moves away from the CNP. The positive curvature of the conductivity versus density is thus proportional to $1/\Gamma^2$ and provides a direct measure of "hydrodynamicity." Another striking signature of hydrodynamics, although more challenging to observe experimentally, would be the value of the Wiedemann-Franz ratio between the electric and thermal resistivity at the CNP, which, from Eqs. (1) and (2), is seen to be proportional to $1/\Gamma^2$. The position of a maximum in the Seebeck coefficient, which is predicted to occur at $\alpha \bar{\mu} = \Gamma$, would be yet another signature. The behavior of the key parameter Γ as a function of temperature and twist angle is summarized in Fig. 4, which we hope will be a valuable guide to experimentalists hunting for signatures of hydrodynamic transport in tBLG.

This paper is organized as follows. In Sec. II, we first evaluate the angle dependence of the screened intrinsic electric and thermal resistivities. In Sec. III, we obtain the resistivities associated with the long-range charged impurity as well as the gauge phonons. Having the key ingredients, i.e., ρ_C and Γ , in Sec. IV we calculate the electric resistivities and the Seebeck coefficient, and show that the WF ratio—a direct indicator of the hydrodynamic regime—is strongly enhanced at the CNP as the magic angle is approached. Section V presents our outlook and conclusions.

II. INTRINSIC RESISTIVITY

At low densities around the CNP, the energy spectrum of tBLG can be approximated by the Dirac model $\epsilon_{\mathbf{k},\pm} = \pm \hbar \tilde{v} k$ with a twist angle-dependent Fermi velocity \tilde{v} ,

$$\tilde{v} = \frac{1 - 3\lambda^2}{1 + 6\lambda^2}, \ \lambda = \frac{w}{\hbar v \Delta K}, \ \Delta K \approx k_D \theta,$$
 (4)

where \tilde{v} is in units of the graphene Fermi velocity $v \simeq 10^6 \text{ m/s}$, θ is the twist angle, w = 110 meV is the interlayer hopping, and $k_D = 4\pi/3a$ with a = 0.246 nm is the graphene lattice constant. Comparing with the tight-binding band structure, the authors in Ref. [19] show that the Dirac model is a valid model at densities $n \lesssim 8 \times 10^{10} \text{ cm}^{-2}$ and for twist angles $\theta \gtrsim 1^{\circ}$.

In our recent work [18], we have demonstrated that within a Dirac model and *in the absence of any disorder* (i.e., for $\Gamma = 0$), the electrical and thermal resistivities can be identified as

$$\rho_{\rm el,C}(0) = \rho_{\rm C} = I_{\rm C} a^2 / e^2, \quad \rho_{\rm el,C}(\bar{\mu} \neq 0) = 0,
\rho_{\rm th,C}(0) = 0, \quad \rho_{\rm th,C}(\bar{\mu} \neq 0) = I_{\rm C} b^2 / \left(k_B^2 T\right),$$
(5)

where $I_{\rm C}(\bar{\mu}, T)$ is the Coulomb collision kernel, given by Eq. (21) in Ref. [18], $a \sim \pi \beta \hbar^2 / \ln 4$, and $b \sim [2\pi \beta \hbar^2 / 9\zeta(3)]\bar{\mu}$ for $\bar{\mu} \rightarrow 0$. The *intrinsic* electric resistivity $\rho_{\rm C}$ (first calculated in Refs. [16,17] for graphene) is associated with the Coulomb drag between the electrons and holes at the CNP ($\mu = 0$). In agreement with Refs. [16,17], we find that in the absence of screening,

$$\rho_{\rm C}^{\rm unscreened} = I_{\rm C}^{\rm unscreened} a^2 \propto \tilde{v}^{-2}.$$
 (6)

With screening, the bare Coulomb interaction v_q is modified to

$$V(q, \omega \to 0) = \frac{v_q}{|1 - v_q \Pi_0|},\tag{7}$$

where, throughout our results in this paper, we have calculated the finite-temperature polarizability $\Pi_0(\mathbf{q}, \omega, T)$ numerically over the full range of frequencies ω and wave vectors \mathbf{q} . To explain the dependence of the resistivities on the renormalized Fermi velocity \tilde{v} close to the CNP, we employ the asymptotic low-frequency form of $\Pi_0(\mathbf{q}, \omega \to 0, T)$ at $T \gg T_F$ [20,21],

$$\Pi_0(\mathbf{q}, T) = \frac{8k_F}{2\pi\hbar\tilde{\nu}} \left[\frac{T}{T_F} \ln 4 + \frac{1}{24} \frac{q^2}{k_F^2} \frac{T_F}{T} \right], \tag{8}$$

using which we can write

$$\rho_{\rm C} \sim \frac{\rho_{\rm C}^{\rm unscreened}}{|1 - v_q \Pi_0|^2} \propto (c + \tilde{v})^{-2},\tag{9}$$

where c has the dimension of a velocity and we obtain its value numerically, e.g., $c \approx 1.2v$ at T = 50 K. In Fig. 1(a), we show

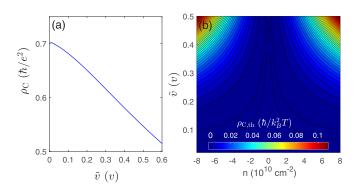


FIG. 1. (a) Electric resistivity $\rho_{\rm C}$ from electron-hole Coulomb scattering at $\bar{\mu} = 0$ (Coulomb drag resistivity) approaches a constant value as the modified Fermi velocity \tilde{v} tends to zero. $\rho_{\rm C}$ also has a very weak (logarithmic) dependence on temperature, which is neglected here. (b) Two-dimensional (2D) contour plot of the intrinsic Coulomb thermal resistivity $\rho_{\rm C,th} \equiv \rho_{\rm C} (\alpha \bar{\mu})^2 e^2 / (k_B^2 T)$ obtained from Eq. (2) in the limit of zero disorder ($\Gamma = 0$) as a function of doping density *n* and \tilde{v} (in units of graphene Fermi velocity *v*) at fixed T = 50 K. Notice that $\rho_{\rm C,th}$ vanishes at $\bar{\mu} = 0$, reflecting the conservation of momentum.

the numerical results for the screened $\rho_{\rm C}$ as a function of \tilde{v} . In contrast to the *T*-dependent $\rho^{\rm unscreened}$, it is interesting to note that the screened $\rho_{\rm C}^{\rm screened}$ has a very weak (logarithmic) dependence on temperature, which is neglected here [17]. At the magic twist angle ($\tilde{v} \rightarrow 0$), we obtain $\rho_{\rm C} \approx 0.7 (\hbar/e^2)$.

In Fig. 1(b), we have shown a 2D contour plot of the Coulomb thermal resistivity $\rho_{C,th}$ as a function of doping density *n* and Fermi velocity \tilde{v} at fixed T = 50 K. At the CNP, $\rho_{C,th}(0)$ vanishes for any value of \tilde{v} ; see Eqs. (5). Within the Dirac model, $n \approx 8\bar{\mu}/[\pi\beta^2(\hbar\tilde{v})^2]$ (note that the Dirac model breaks down at precisely magic twist angle $\tilde{v} = 0$), and therefore away from the CNP, we obtain

$$\rho_{\mathrm{C,th}}(\bar{\mu} \neq 0) = \rho_{\mathrm{C}}(b^2/a^2) \left(e^2/k_B^2 T \right) \propto \rho_{\mathrm{C}} \,\bar{\mu}^2 \propto \frac{\tilde{v}^4}{(c+\tilde{v})^2} \,, \tag{10}$$

which exhibits a substantial suppression of $\rho_{C,th}$ as $\tilde{v} \to 0$, as seen in Fig. 1(b).

III. MOMENTUM-NONCONSERVING COLLISIONS

A. Long-range charged impurity

We now evaluate the contribution of charged impurities and its \tilde{v} dependence within the Dirac-modeled tBLG. We recall that the momentum-nonconserving collision integral of the scattering potential of randomly distributed screened (long-range) impurity charge centers is given by [20]

$$\mathbf{I}_{\text{dis}}(\mathbf{k},\eta) = 8 \times \frac{2\pi n_{\text{imp}}}{\hbar} \sum_{\eta'} \sum_{\mathbf{k}'} \left| \frac{v_q}{1 - v_q \Pi_0(\mathbf{q},T)} \right|^2 F_{\mathbf{k},\mathbf{k}'}^{\eta\eta'} \times (f_{\mathbf{k},\eta} - f_{\mathbf{k}',\eta'}) \delta(\epsilon_{\mathbf{k},\eta} - \epsilon_{\mathbf{k}',\eta'}),$$
(11)

where $\eta(\eta') = \pm 1$ sums over the two bands, $\mathbf{q} = \mathbf{k} - \mathbf{k}'$, and n_{imp} is the disorder density. The factor 8 accounts for the spin and both graphene and Moiré valley degeneracies. Inserting the nonequilibrium distribution function $f = f_0 + f'_0 \mathbf{v}_{\mathbf{k}}$.

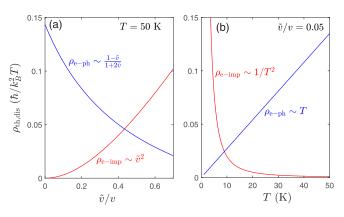


FIG. 2. Thermal resistivity associated with the long-range charged impurity (red curves) and acoustic gauge phonons (blue curves) as functions of (a) \tilde{v}/v (at T = 50 K) and (b) temperature T (at $\tilde{v}/v = 0.05$). Both sets of curves are calculated at the charge-neutrality point and the charged impurity density in (a) is set to $n_{\rm imp} = 1 \times 10^{10}$ cm⁻². $\rho_{\rm th,dis}$ can be linked to the corresponding electric resistivity $\rho_{\rm el,dis}$, through the Wiedemann-Franz law for non-interacting electronic systems, which takes the form $\rho_{\rm el,dis}/\rho_{\rm th,dis} \simeq 2.4\pi^2 k_B^2 T/(3e^2)$ for the Dirac model near charge neutrality.

 $(\mathbf{p}_n + \beta \tilde{\epsilon}_{\mathbf{k},\gamma} \mathbf{p}_s)$, where \mathbf{p}_n and \mathbf{p}_s are the momentum shifts due to the charge and heat (entropy) currents, respectively, we write the linearized collision kernels as

$$I_{\rm imp}^{(m)} = \frac{4n_d}{\hbar^3} \left(\frac{e^2}{\kappa}\right)^2 \int_0^{2\pi} d\theta (1 + \cos\theta) \\ \times \int_0^\infty d\bar{\epsilon} \frac{(\bar{\epsilon} - \bar{\mu})^m f'(\bar{\epsilon}) + (-1)^\alpha (\bar{\epsilon} + \bar{\mu})^m f'(-\bar{\epsilon})}{|\epsilon(\bar{\epsilon}, \theta)|^2},$$
(12)

where m = 0, 1, 2 give the matrix elements I_{imp}^{11} , $I_{imp}^{12} = I_{imp}^{21}$, and I_{imp}^{22} , respectively. $\bar{\epsilon} = \beta \epsilon_{\mathbf{k}}$, $f'(\bar{\epsilon}) = \exp(\bar{\epsilon} - \bar{\mu})/[1 + \exp(\bar{\epsilon} - \bar{\mu})]^2$, and, using Eq. (8), the dielectric function $\varepsilon(\bar{\epsilon}, \theta)$ is

$$\varepsilon(\bar{\epsilon},\theta) = 1 + \frac{8(e^2/\kappa)}{\hbar\tilde{v}\sqrt{2(1-\cos\theta)}} \left[\frac{\ln 4}{\bar{\epsilon}} + \frac{\bar{\epsilon}}{12}\right].$$
 (13)

The resistivity matrix is obtained using $\rho = \mathbf{D}^{-1} \cdot \mathbf{I}_{imp} \cdot \mathbf{D}^{-1}$, where **D** is a symmetric 2 × 2 matrix of *Drude weights*, which are functions of $\bar{\mu}$. These functions are calculated analytically in Ref. [18] and do not depend on \tilde{v} since we work within the same Dirac model. Therefore, the \tilde{v} dependence of $\rho_{dis,th}$ is completely defined through the \tilde{v} dependence of \mathbf{I}_{imp} ,

$$\rho_{\rm imp,th}^{\rm long-range}(\tilde{v}\to 0)\propto \tilde{v}^2.$$
(14)

The red curves in Figs. 2(a) and 2(b) show, respectively, the \tilde{v} and T dependence of $\rho_{\rm imp,th}$ at the CNP (n = 0). We note that $\rho_{\rm th,dis}$ can be linked to the disorder electric resistivity $\rho_{\rm el,dis}$, through the standard WF relation, i.e., for the Dirac model $\rho_{\rm el,dis}/\rho_{\rm th,dis} \simeq 2.4\pi^2 k_B^2 T/(3e^2)$. While we see that $\mathbf{I}_{\rm imp}$ in Eq. (12) is independent of T, the T dependence of the $\rho_{\rm imp}$ [see Fig. 2(b)] comes entirely from the $1/T^2$ dependence of the inverse Drude weights.

B. Gauge phonons

In addition to the long-range charge impurities, the importance of phonons has been highlighted in the recent theoretical and experimental literature, e.g., Refs. [15,19,22]. We leave a detailed discussion of the differences between the theoretical formulations and the degree to which it explains available experimental data to a future paper [23]. For our purposes, we need the collision integral for electron-phonon scattering that is given by

$$\mathbf{I}_{\mathrm{e-ph}} = \sum_{\mathbf{k}', \lambda' = \pm 1} W_{\mathbf{k}'\mathbf{k}}^{\lambda'\lambda} f_{\mathbf{k}',\lambda'} (1 - f_{\mathbf{k},\lambda}) - W_{\mathbf{k}\mathbf{k}'}^{\lambda\lambda'} f_{\mathbf{k},\lambda} (1 - f_{\mathbf{k}',\lambda'}),$$
(15)

where $W_{\mathbf{k'k}}^{\lambda'\lambda}$ is the probability of scattering from state $|\mathbf{k}, \lambda\rangle$ to state $|\mathbf{k'}, \lambda'\rangle$ [with $\lambda(\lambda') = \pm 1$ are band indices], given by

$$W_{\mathbf{k},\mathbf{k}+\mathbf{q}}^{\lambda\lambda'} = \frac{2\pi}{\hbar} |g_{\mathbf{kq}}^{\lambda\lambda'}|^2 [N_{\mathbf{q}}\delta(\epsilon_{\mathbf{k}+\mathbf{q},\lambda'} - \epsilon_{\mathbf{k},\lambda} - \hbar v_A q) + (1+N_{\mathbf{q}})\delta(\epsilon_{\mathbf{k}+\mathbf{q},\lambda'}^m - \epsilon_{\mathbf{k},\lambda} + \hbar v_A q)], \quad (16)$$

which describes phonon absorption and emission. Here, $N_{\mathbf{q}} = 1/\{\exp[\hbar v_A q/(k_B T)] - 1\}$ is the Bose-Einstein distribution function and $g_{\mathbf{kq}}^{\lambda\lambda'}$ is electron-phonon coupling, given by

$$g_{\mathbf{kq}}^{\lambda\lambda'} = \tilde{\beta}_A q \sqrt{\frac{2\hbar}{A\rho\omega_{\mathbf{q}}}} F_{\mathbf{k},\mathbf{k+q}}^{\lambda\lambda'}, \qquad (17)$$

with effective gauge phonon coupling constant $\tilde{\beta}_A$ and chirality factor $F_{\mathbf{k}\mathbf{k}'}^{\lambda\lambda'} = (1 + \lambda\lambda' \cos\theta_{\mathbf{k},\mathbf{k}'})/2$. Employing the ansatz $f_{\mathbf{k},\lambda} = f_{\mathbf{k},\lambda}^0 + \lambda e E \tilde{v} \cos\theta_{\mathbf{k}} \tau_{\mathbf{k},\lambda} (\partial f_{\mathbf{k},\lambda}^0 / \partial \epsilon_{\mathbf{k},\lambda})$, we obtain (up to linear order) the electron-phonon scattering time,

$$\frac{1}{\tau_{\mathrm{e-ph}}^{\lambda}(\mathbf{k})} = \sum_{\mathbf{k}',\lambda'} W_{\mathbf{k}'\mathbf{k}}^{\lambda'\lambda} \frac{1 - f_{\mathbf{k}',\lambda'}^{0}}{1 - f_{\mathbf{k},\lambda}^{0}} (1 - \lambda\lambda' \cos\theta_{\mathbf{k},\mathbf{k}'}), \quad (18)$$

which can be evaluated numerically. For this work, we use $\mu_s = 7.66 \times 10^{-7} \text{ kg/m}^2$ for the mass density of graphene, $v_A = 1.62 \times 10^4 \text{ m/s}$ is the effective acoustic phonon velocity, and $\tilde{\beta}_A \approx \beta_A(\tilde{v}/v_F)/[2 \tan(\theta/2)]$ is the effective electronphonon coupling constant [19], where $\beta_A = 3.6 \text{ eV}$ is the best estimate for monolayer graphene determined from density functional perturbation theory and tight-binding calculations [24,25].

The contribution of gauge phonon limited resistivity is obtained by averaging

$$\frac{1}{\rho_{\rm e-ph}} = e^2 \int_{-\infty}^{\infty} d\epsilon N_D(\epsilon) \frac{\tilde{v}^2}{2} \tau_{\rm e-ph}(\epsilon) [-f_0'(\epsilon)], \qquad (19)$$

where $N_D(\epsilon) = 4|\epsilon|/[\pi (\hbar \tilde{v})^2]$ is the density of states and $\tau_{e-ph}(\epsilon)$ is the electron-phonon scattering time (18). At $\tilde{v}/v_A \gtrsim 2$, we can use quasielastic approximations and obtain

$$\rho_{\rm e-ph}(T \ll T_{\rm BG}) \simeq \frac{1}{\tilde{v}^2} \frac{48\zeta(4)\tilde{\beta}_A^2(k_B T)^4}{e^2\hbar^4 \mu_s v_A^5 (\pi |n|)^{3/2}},$$

$$\rho_{\rm e-ph}(T \gg T_{\rm BG}) \simeq \frac{1}{\tilde{v}^2} \frac{\pi \tilde{\beta}_A^2 k_B T}{2e^2\hbar \mu_s v_A^2}.$$
(20)

In both cases, ρ_{e-ph} is proportional to $(\tilde{\beta}_A/\tilde{v})^2 \propto 1/\tan^2(\theta/2) \sim (1-\tilde{v})/(1+2\tilde{v})$ at fixed T and linearly

TABLE I. The dependence of relevant resistivities on Fermi velocity \tilde{v} and temperature *T* for $T \gg T_F$.

Resistivity	\tilde{v} dependence	T dependence
Intrinsic e-h Coulomb $\rho_{\rm C}^{\rm screened}$ Long-range charged impurity $\rho_{\rm e-imp}$	· · · · ·	independent $1/T^2$
	$\tilde{v}(1-\tilde{v})/(1+2\tilde{v})$ \tilde{v}^4	T T

 $^{a}v_{A} = 1.62 \times 10^{4} \text{ m/s}$ is the effective acoustic phonon velocity.

increases with *T* for $T \gg T_{BG}$, where T_{BG} is the Bloch-Gruneisen temperature $(k_B T_{BG} = 2\hbar v_A k_F)$ (see the blue curves in Fig. 2). In the limit of $\tilde{v} \rightarrow 0$, the interband scattering dominates and this changes the dependence on \tilde{v} [23]. In particular, for $T \gg T_F$, while ρ_{e-ph} remains linear with *T*, it scales as \tilde{v}^4 at fixed *T*. The dependence of the considered resistivities on the renormalized Fermi velocity \tilde{v} and temperature *T* is summarized in Table I.

In Figs. 3(a) and 3(b), we, respectively, show the total electric resistivity ρ_{el}^{total} , defined in Eq. (1), and the noninteracting (only the charged impurity and gauge-phonon contributions) electric resistivity ρ_{el}^{dis} as functions of \tilde{v} and doping density n. The total resistivity ρ_{el}^{total} follows the Lorentzian form of Eq. (1) as a function of density ($n \propto \mu$). When $\mu \rightarrow 0$, the relevant contribution is the Coulomb term ρ_{C} , i.e., $\rho_{el} \rightarrow \rho_{C}$, which increases as $\tilde{v} \rightarrow 0$. In the absence of Coulomb interactions, we observe that the \tilde{v} and density dependence of ρ_{el}^{dis} is completely dominated by the behavior of the total contributions of $\rho_{el,imp} + \rho_{el,e-ph}$ [see Fig. 2(a)]. Accordingly, we observe a minimum in Fig. 3(b) at $\tilde{v} \sim 0.4$. As a function of density, it is interesting to note that ρ_{el}^{dis} is density independent at small \tilde{v} , where the gauge phonons dominate. Although the WF ratio and $1/\Gamma^2$ are the main parameters for identifying the hydrodynamic regime, we note that ρ_{el} has a localized

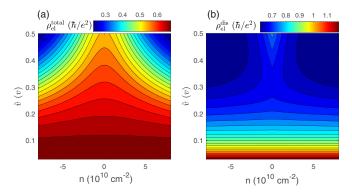


FIG. 3. (a) Contour plot of the total electric resistivity, given by Eq. (1)—including the contributions of charged impurities, gauge phonons, and Coulomb scattering—as a function of \tilde{v}/v and doping density *n* at fixed T = 50 K. The charged impurity density is set to $n_{imp} = 1 \times 10^{10}$ cm⁻². (b) Same plot for the noninteracting electric resistivity, including only charged impurity and gauge-phonon scattering: $\rho_{el}^{dis} = \rho_{el,imp} + \rho_{el,e-ph}$. Observe how the total resistivity in (a) decreases sharply with increasing doping density, in contrast to ρ_{el}^{dis} in (b), which is weakly density dependent. Thus, a sharp peak of ρ_{el}^{total} around the charge-neutrality point constitutes experimental evidence of strong hydrodynamic transport.

peak around the CNP. This is the opposite behavior from the noninteracting contributions and observing this feature in the experiments would be an immediate indication of strong hydrodynamic transport directly from electrical conductivity measurements. The strong density dependence of the electric resistivity on a scale controlled by Γ near the CNP can be, in general, used as a signature of hydrodynamic transport in semimetals with dominating electron-hole scattering; e.g., see Refs. [26,27].

C. Calculation of Γ

We define the parameter $1/\Gamma^2$, where Γ is given in Eq. (3), as a *hydrodynamic* parameter which shows the strength of the momentum-nonconserving disorder collisions vs the intrinsic electron-hole momentum-conserving Coulomb collisions,

$$\frac{1}{\Gamma^2} \propto \frac{\rho_{\rm C}}{\rho_{\rm th,imp} + \rho_{\rm th,ph}} \equiv \frac{\tau_{\rm eh}^{-1}}{\tau_{\rm imp}^{-1} + \tau_{\rm ph}^{-1}}.$$
 (21)

Note that at the CNP, $1/\Gamma^2$ is the physical thermoelectric parameter WF(0), which is given at finite doping density by the square Lorentzian law [18]

WF(
$$\bar{\mu}$$
) $\simeq \left[\frac{\Gamma}{\Gamma^2 + (\alpha \bar{\mu})^2}\right]^2 \left(\frac{k_B}{e}\right)^2$. (22)

In Fig. 4, we mapped out the $(T - \tilde{v})$ 2D contour plot of $1/\Gamma^2$ at velocities very close to the magic angle and at low temperatures. We point out that Γ has a weak dependence on the doping density *n* around the CNP [see Fig. 3(b)]. When $\tilde{v} \rightarrow 0$, ρ_{e-ph} is the dominant disorder mechanism which linearly increases with *T*. At the other limit $\tilde{v} \rightarrow 1$ (which is the case of monolayer graphene), ρ_{e-imp} becomes

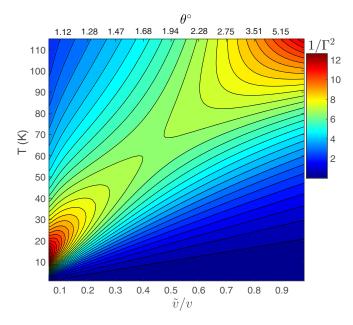


FIG. 4. Contour plot of $1/\Gamma^2$ in the $(T - \tilde{v})$ plane, where Γ , defined in Eq. (3), determines the width in density of the hydrodynamic transport region. An enhanced "hydrodynamic window" characterized by exceptionally large values of $1/\Gamma^2 \simeq 10$ is clearly visible in a range of twist angles on the left side of the figure.

important and decays as $1/T^2$ (see Fig. 2). Since ρ_C is fairly independent of T (has a weakly logarithmic dependency) and slowly varying with \tilde{v} [see Fig. 1(a)], the competition between ρ_{e-imp} and ρ_{e-ph} in Eq. (21) results in the two different regions with stronger hydrodynamic effects $(1/\Gamma^2 \gg 1)$ in Fig. 4: (i) near magic angle and for $10 \leq T \leq 50$ K, and (ii) $\tilde{v} \rightarrow 1$ with $T \gtrsim 70$ K (we have neglected the effect of acoustic phonons which are relevant for $T \gtrsim 150$ K in graphene [28] and should suppress the hydrodynamicity as T increases). The crossover between these two regions occurs at $\tilde{v} \sim 0.4$, associated with the velocity at which $\rho_{e-ph} = \rho_{e-imp}$ [see Fig. 2(a)].

IV. WIEDEMAN-FRANZ RATIO AND SEEBECK COEFFICIENT

Having all the ingredients, we can now calculate the WF [see Eq. (22)], as well as the Seebeck coefficient, which near the CNP takes the form [18]

$$Q(\bar{\mu}) \simeq -\frac{\alpha \bar{\mu}}{(\alpha \bar{\mu})^2 + \Gamma^2} \frac{k_B}{e}.$$
 (23)

Figures 5(a) and 5(b) show, respectively, the results for the WF and the Seebeck coefficient, including the contribution of both the charged impurity and gauge phonons as functions of doping density n and renormalized Fermi velocity (alias twist angle) \tilde{v} . For clarity, WF is scaled with the Lorentz number $\pi^2 k_B^2/3e^2$ and shown as ln(WF). Consistent with the results in Fig. 4, where at T = 50 K, $1/\Gamma^2$ is large for $0.1 \lesssim \tilde{v} \lesssim 0.45$, we observe a large enhancement of the WF at these near magic twist angle velocities. The broadening of the square-Lorentzian WF peak when $\tilde{v} \rightarrow 0$, i.e., approaching the magic twist angle, is caused by the density-independent ρ_{e-ph} , which is the dominant disorder scattering mechanism in this regime. As seen in Fig. 3(b), ρ_{dis} becomes density independent at small \tilde{v} , while it decreases as a function of density as \tilde{v} increases. Therefore, we observe that the Seebeck coefficient in Fig. 5(b), which is proportional to $\bar{\mu} \propto n$, peaks at twist angles corresponding to $\tilde{v} \gtrsim 0.4$.

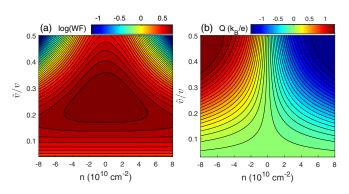


FIG. 5. Contour plot of (a) ln(WF) and (b) Seebeck coefficient Q as a function of doping density n and Fermi velocity \tilde{v} at T = 50 K. WF is scaled with the Lorentz number $\pi^2 k_B^2/3e^2$ and the charged impurity density is set to $n_{\rm imp} = 1 \times 10^{10}$ cm⁻². The large enhancement of the WF and the peak in the Seebeck coefficient at small \tilde{v} are both signatures of the hydrodynamic regime.

V. CONCLUDING REMARKS

In this paper, we have calculated the transport properties of twisted bilayer graphene near magic twist angle and at low densities around the charge-neutrality point (K point). We have obtained our results for the electric and thermal resistivities, the Wiedemann-Franz ratio, and the Seebeck coefficient. Momentum-nonconserving scattering mechanisms, such as long-range (screened) charge impurities and acoustic gauge phonons, which become most relevant in twisted bilayer graphene near the magic angle, are all included in a single parameter $\Gamma \ll 1$, which controls the doping density dependence of the thermoelectric transport coefficients in a region of $\mu/(k_BT) \ll 1$ around the charge-neutrality point. Including the effect of screening, we obtained (renormalized) Fermi velocity \tilde{v} dependence of the resistivities pertinent to the e-h Coulomb interaction, long-range charged impurities, and the gauge phonons (see Table I).

Our most interesting result is that the hydrodynamic transport anomaly, characterized by large values of the WF ratio

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and the Seebeck coefficient, is very strong in the vicinity of the magic twist angle and in a temperature range of $10 \leq T \leq$ 50 K, where the gauge phonons are the dominant disorder mechanism. Besides the enhanced thermoelectric coefficients that we have studied here, twisted bilayer graphene could also be an interesting system for the realization of nonlinear hydrodynamic effects such as turbulent viscous electron flow [29]. This is due to the large fine-structure constant at the magic twist angle which leads to a low viscosity-to-entropy ratio.

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